

NuPhotonics

Rev. 0.9 – Feb. 2024

Part Number: S001T67
Product State: Production Build

9 KHz – 67 GHz Absorptive SPDT Switch

Description

S001T67 is an ultrawide band (UWB) absorptive single pole double through (SPDT) RF switch. The outputs are terminated to 50 Ω load in the isolated path. It offers 24 dBm of power handling. The device offers Low voltage logic levels which make this device compatible with CMOS logic. The RF outputs are DC-coupled.

Features

- Coaxial package
- Low insertion loss
 - o 1.5 dB @ 10 GHz
 - o 2 dB @ 30 GHz
 - o 3 dB @ 40 GHz
 - o 4 dB @ 60 GHz
- 15 dB return loss
- Broad temperature operating range
- No low Frequency Spurious emissions
- 40 dB Reverse isolation
- 1.85 mm connectors
- 24 dBm switching power handling





Applications

- Communication systems
- Datacenters
- Test and Measurement



Electrical Specifications (T_{op} 23 \pm 3°c, unless otherwise specified)

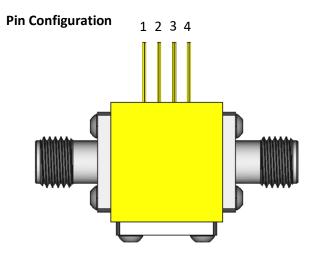
Parameter	Min.	Тур.	Max.	Unit	Test Conditions
Insertion Loss		1.5			9 KHz – 18 GHz
		2		dB	18 – 30 GHz
		3			30– 45 GHz
		4			45 – 67 GHz
Isolation RF1 to RF2		60			9KHz - 20 GHz
		50		dB	20 – 40 GHz
		40			40 – 67 GHz
	50	55			9 KHz -20 GHz
Isolation RFC to RF1/RF2	35	40		dB	20 – 40 GHz
	30	38			40 – 67 GHz
RFin Return loss		25			9 KHz -20 GHz
		18		dB	20 – 40 GHz
		15			40 – 67 GHz
		20			9 KHz – 20 GHz
RF1/RF2 Return loss		18		dB	20 – 40 GHz
		15			40 – 67 GHz
T _{ON}		0.9		μs	50% control to 90%
T _{OFF}		0.2		μs	50% control to 10%
T_{RISE}		0.4		μs	10% to 90%
T _{FALL}		0.06		μs	90% to 10%
Input P1dB		28		dBm	10 MHz – 27 GHz
Input IP3		50		dBm	10 MHz – 27 GHz / Two tone, 1 MHz tone separation

Absolute Maximum Ratings

Parameter	Symbol	Condition	Min.	Max.	Unit
VSS	V _{SS}		-3.5	0	V
VCC/VC1/VC2			0	3.5	V
Storage Temperature	T_{stg}		-65	120	°C
Storage Humidity	H_{stg}			85	% r.H.
Operating Temperature	T _{op}		-40	85	°C
ESD Susceptibility ¹		НВМ		1000	V
Input Power	P _{in}	CW		24	dBm

Operating at maximum ratings for a prolonged period will cause damage to the device.

 $^{^{\}rm 1}\,$ ESD sensitive device, proper ESD protection procedures must be followed.



Pin Number	Function		
1	VSS		
2	Control Voltage 1 (V _{C1})		
3	Control Voltage 2 (V _{C2})		
4	VCC		

Truth Table

VC1	VC2	RF _{out1}	RF _{out2}					
Low	Low	Off	On					
Low	High	On	Off					
High	Low	Off	Off					
High	High	Off	Off					

Off signifies that the RF output is connected to the device 50Ω load On signifies RF out is connected to RF in



Recommended Bias Sequence

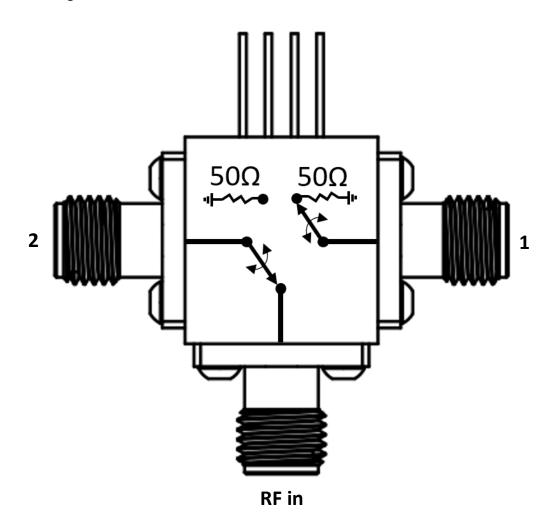
Power on:

- 1.) Apply VCC Bias
- 2.) Apply VSS Bias
- 3.) Apply Control Bias

Power off:

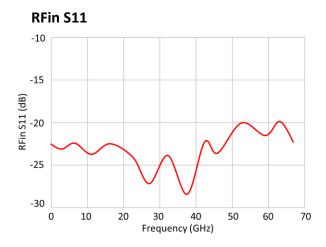
- 1.) Remove Control Bias
- 2.) Remove VSS Bias
- 3.) Remove VCC Bias

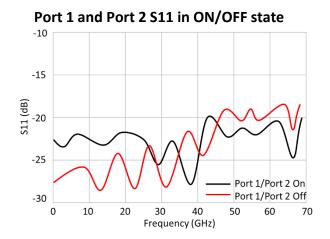
Functional Diagram

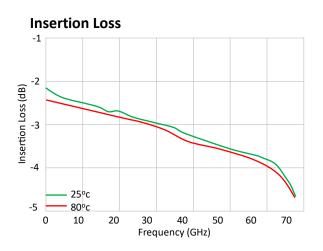


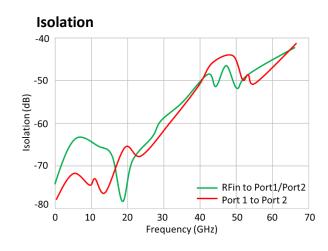


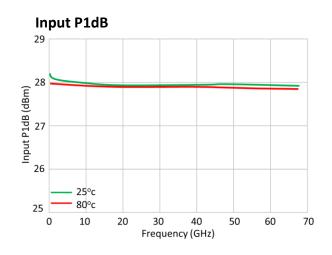
Typical performnace curves (T_{op} 23 ± 3°c)

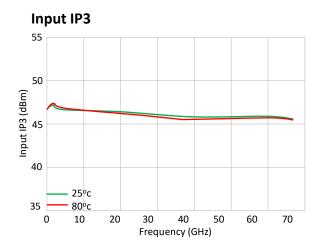












Device Dimensions (all units in mm)

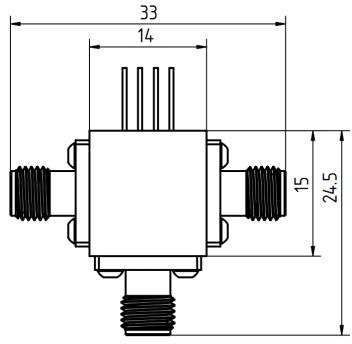
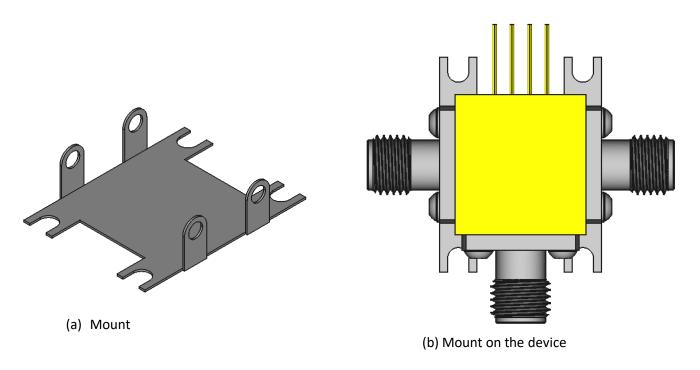


Figure 1. All units in mm. Manufactured device sizes may differ.

Optional Mount: If is desirable to mechanically fix the device in place. An optional Mount can be added to the device.





Inquiry Information

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General: If you are interested in a custom solution, general information, or engineering related information please contact Inquiry@NuPhotonics.com

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Definitions: Product State

Alpha Build: Devices in Alpha build are in internal engineering build and testing stages. Major changes may happen for production build.

Beta Build: Devices in Beta build are for external customer and engineering sample testing stages. Minor changes may happen for production build.

Production Build: Customer ready devices. Small appearance changes may occur between devices.

Obsolete: Currently not supported.

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